SHANGHAI SUNRISE ELECTRONICS CO., LTD.

KBP005 THRU KBP10 SINGLE PHASE SILICON

BRIDGE RECTIFIER

TECHNICAL SPECIFICATION

VOLTAGE: 50 TO 1000V

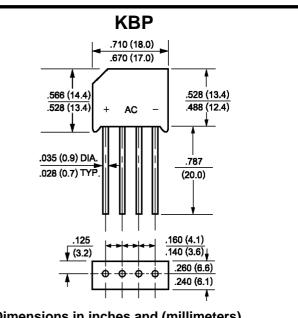
CURRENT: 2.0A

FEATURES

- Ideal for printed circuit board
- Surge overload rating: 60 A peak
- High case dielectric strength
- High temperature soldering guaranteed: 250°C/10sec/0.375"(9.5mm) lead length at 5 lbs tension

MECHANICAL DATA

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	KBP 005	KBP 01	KBP 02	KBP 04	KBP 06	KBP 08	KBP 10	UNITS
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $(T_a=50^{\circ}C)$	I _{F(AV)}	2.0						А	
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I _{FSM}	60						A	
Maximum Instantaneous Forward Voltage (at forward current 2.0A DC)	V _F	1.1						V	
Maximum DC Reverse Current $T_a=25^{\circ}C$ (at rated DC blocking voltage) $T_a=100^{\circ}C$		10.0 500							μΑ μΑ
Operating Temperature Range	Τ _J	-55 to +125							О°
Storage Temperature	T _{STG}	-55 to +150						٥C	

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